

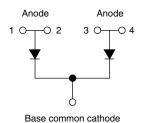
Vishay High Power Products

Not Insulated SOT-227 Power Module Ultrafast Rectifier, 200 A

Ultrafast Rectifier, 200 A FEATURES



SOT-227



| PRODUCT SUMMARY | | | | | |
|---|--------|--|--|--|--|
| V_{R} | 600 V | | | | |
| $I_{F(AV)}$ at T_C = 136 °C per module ⁽¹⁾ | 200 A | | | | |
| t _{rr} | 111 ns | | | | |

Note

- Not insulated package
- · Ultrafast reverse recovery
- Ultrasoft reverse recovery current shape
- · Low forward voltage
- Optimized for power conversion: welding and industrial SMPS applications
- Plug-in compatible with other SOT-227 packages
- · Easy to assemble
- · Direct mounting to heatsink
- Compliant to RoHS directive 2002/95/EC
- · Designed and qualified for industrial level

DESCRIPTION

The UFL200CB60P not insulated modules integrate two state of the art ultrafast recovery rectifiers in the compact, industry standard SOT-227 package. The planar structure of the diodes, and the platinum doping life time control, provide a ultrasoft recovery current shape, together with the best overall performance, ruggedness and reliability characteristics.

These devices are thus intended for high frequency applications in which the switching energy is designed not to be predominant portion of the total energy, such as in the output rectification stage of welding machines, SMPS, dc-to-dc converters. Their extremely optimized stored charge and low recovery current reduce both over dissipation in the switching elements (and snubbers) and EMI/RFI.

| ABSOLUTE MAXIMUM RATINGS | | | | | |
|---|-----------------------------------|-------------------------|-------------|-------|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | MAX. | UNITS | |
| Cathode to anode voltage | V_R | | 600 | V | |
| Continuous forward current per diode | I _F ⁽¹⁾ | T _C = 129 °C | 142 | ^ | |
| Single pulse forward current per diode | I _{FSM} ⁽²⁾ | T _C = 25 °C | 1000 | Α | |
| Maximum power dissipation per module | P_D | T _C = 129 °C | 484 | W | |
| Operating junction and storage temperatures | T _J , T _{Stg} | | - 55 to 175 | °C | |

Notes

⁽¹⁾ All 4 anode terminals connected

⁽¹⁾ Both anode terminals connected;

Maximum I_{RMS} current per leg 200 A to do not exceed the maximum temperature of terminals, see fig. 6

^{(2) 10} ms sine or 6 ms rectangular pulse

UFL200CB60P



Vishay High Power Products Not Insulated SOT-227 Power Module Ultrafast Rectifier, 200 A

| ELECTRICAL SPECIFICATIONS PER DIODE (T _J = 25 °C unless otherwise specified) | | | | | | |
|--|---|--|------|------|------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS |
| Cathode to anode breakdown voltage | V_{BR} | V _{BR} I _R = 100 μA | | - | - | |
| Forward voltage V _{FM} | V_{FM} | I _F = 100 A | - | 1.21 | 1.44 | V |
| | | I _F = 100 A, T _J = 125 °C | - | 1.09 | 1.24 | |
| | | I _F = 200 A | - | 1.41 | 1.66 | |
| | I _F = 200 A, T _J = 125 °C | - | 1.33 | 1.55 | | |
| Reverse leakage current I _{RM} | I | $V_R = V_R$ rated | - | - | 100 | μΑ |
| | IRM | $T_J = 175 ^{\circ}\text{C}, V_R = V_R \text{rated}$ | - | - | 1 | mA |
| Junction capacitance | C _T | V _R = 600 V | - | 80 | - | pF |

| DYNAMIC RECOVERY CHARACTERISTICS PER DIODE (T _J = 25 °C unless otherwise specified) | | | | | | | |
|---|---------------------------------|--|--|------|------|------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | MIN. | TYP. | MAX. | UNITS |
| | | $I_F = 1.0 \text{ A}, dI_F/dt = 400 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$ | | - | 41 | - | |
| Reverse recovery time | e recovery time t _{rr} | T _J = 25 °C | | - | 111 | 141 | ns |
| | | T _J = 125 °C | $I_F = 50 \text{ A}$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_R = 200 \text{ V}$ | - | 215 | 293 | |
| Peak recovery current | | T _J = 25 °C | | - | 11 | 14 | А |
| | IRRM | T _J = 125 °C | | - | 23 | 27 | |
| Reverse recovery charge | 0 | T _J = 25 °C | | - | 610 | 990 | nC |
| | Q _{rr} | T _J = 125 °C | | - | 2470 | 3955 | |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | |
|---|-------------------|-----------------------|------|------|-------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS |
| Junction to case, single leg conducting | В | | - | - | 0.19 | |
| Junction to case, both leg conducting | R _{thJC} | | - | - | 0.095 | °C/W |
| Case to heatsink, per module | R _{thCS} | Flat, greased surface | - | 0.05 | - | |
| Weight | | | - | 30 | - | g |
| Mounting torque | | | - | 1.3 | - | Nm |

Document Number: 94277 Revision: 16-Jul-09



Not Insulated SOT-227 Power Module Vishay High Power Products Ultrafast Rectifier, 200 A

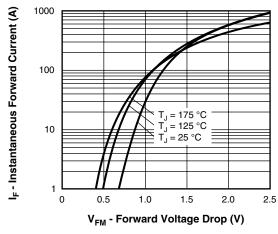


Fig. 1 - Typical Forward Voltage Drop Characteristics (Per Diode)

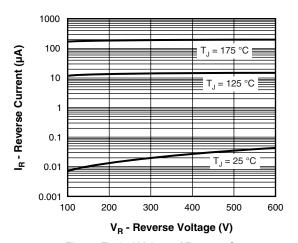


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

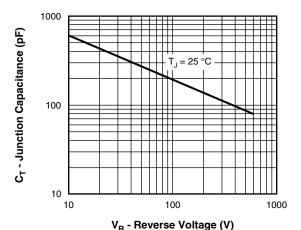


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

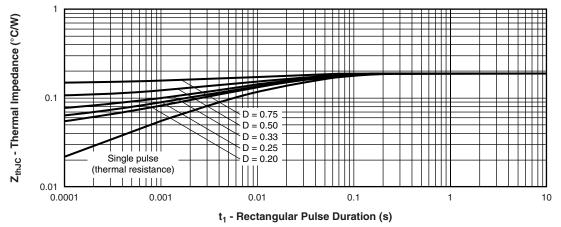


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Diode)

VISHAY

Vishay High Power Products Not Insulated SOT-227 Power Module Ultrafast Rectifier, 200 A

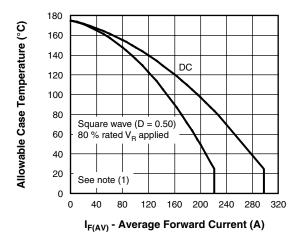


Fig. 5 - Maximum Allowable Case Temperature vs. Avarage Forward Current (Per Leg)

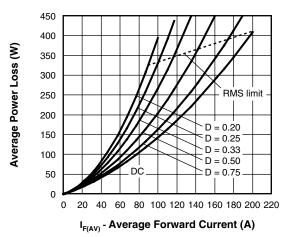


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

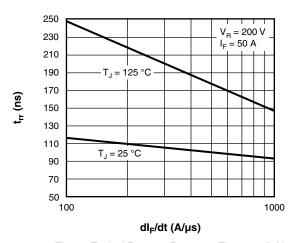


Fig. 7 - Typical Reverse Recovery Time vs. dI_F/dt

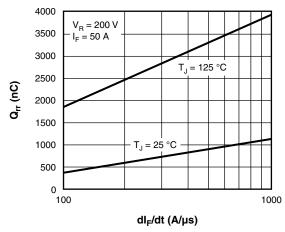


Fig. 8 - Reverse Recovery Charge vs. dl_F/dt

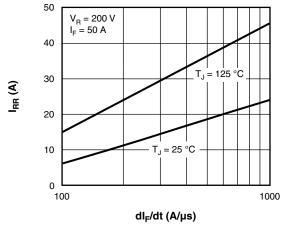


Fig. 9 - Typical Reverse Recovery Current vs. dl_F/dt

Note

 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{th,JC}; Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R



Not Insulated SOT-227 Power Module Vishay High Power Products Ultrafast Rectifier, 200 A

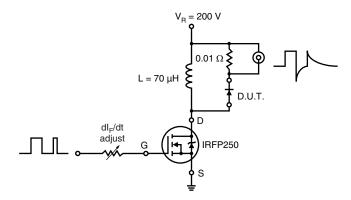
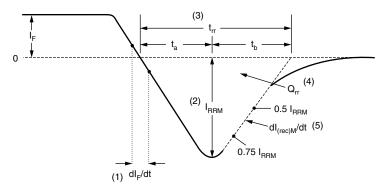


Fig. 10 - Reverse Recovery Parameter Test Circuit



- (1) dl_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.
- (4) $\mathbf{Q}_{\rm rr}$ area under curve defined by $\mathbf{t}_{\rm rr}$ and $\mathbf{I}_{\rm RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) dl_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

Fig. 11 - Reverse Recovery Waveform and Definitions

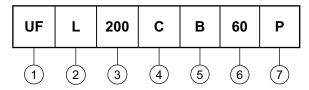
UFL200CB60P

Vishay High Power Products Not Insulated SOT-227 Power Module Ultrafast Rectifier, 200 A



ORDERING INFORMATION TABLE

Device code



1 - Ultrafast rectifier

2 - Ultrafast Pt Low V_F

- Current rating (200 = 200 A)

4 - Circuit configuration (2 common cathode diodes)

- Package indicator (SOT-227 standard not insulated)

6 - Voltage rating (60 = 600 V)

7 - • P = Lead (Pb)-free

Quantity per tube is 10 pcs, M4 screw and washer included

| LINKS TO RELATED DOCUMENTS | | | | |
|---|--|--|--|--|
| Dimensions <u>www.vishay.com/doc?95036</u> | | | | |
| Packaging information <u>www.vishay.com/doc?95037</u> | | | | |





Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk and agree to fully indemnify and hold Vishay and its distributors harmless from and against any and all claims, liabilities, expenses and damages arising or resulting in connection with such use or sale, including attorneys fees, even if such claim alleges that Vishay or its distributor was negligent regarding the design or manufacture of the part. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Revision: 11-Mar-11